

## 产品规格书

### Specification of products

产品名称: 快恢复二极管

产品型号: MFK200U4-K2

浙江世菱半导体有限公司  
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

地址: 浙江省 丽水市 莲都区

电话: (0578) 3012571 3615078

传真: (0578) 3611180

邮编: 323000

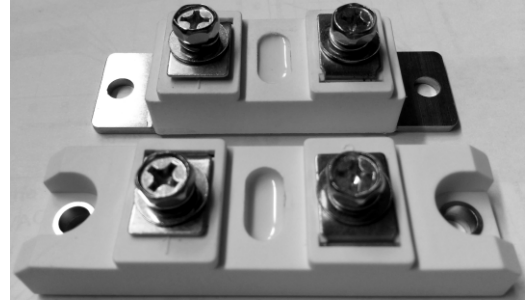
E-mail: smrshiling01@163.com

Http://www.smrshiling.com

拟制	审核	核准
林益龙	曹剑龙	宗瑞

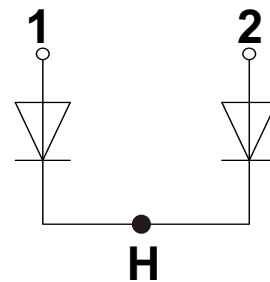
### PRODUCT FEATURES

- ☑ Ultrafast Reverse Recovery Time
- ☑ Soft Reverse Recovery Characteristics
- ☑ Low Reverse Recovery Loss
- ☑ Low Forward Voltage
- ☑ High Surge Current Capability
- ☑ Low Inductance Package



### APPLICATIONS

- ☑ Inversion Welder
- ☑ Uninterruptible Power Supply
- ☑ Plating Power Supply
- ☑ Ultrasonic Cleaner and Welder
- ☑ Converter & Chopper
- ☑ Power Factor Correction (PFC) Circuit



### ABSOLUTE MAXIMUM RATINGS

$T_C=25^{\circ}\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
$V_R$	Maximum D.C. Reverse Voltage		400	V
$V_{RRM}$	Maximum Repetitive Reverse Voltage		400	V
$I_{F(AV)}$	Average Forward Current	$T_C=110^{\circ}\text{C}$ , Per Diode	100	A
		$T_C=110^{\circ}\text{C}$ , Per Moudle	200	A
		$T_C=110^{\circ}\text{C}$ , 20KHz, Per Moudle	100	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=110^{\circ}\text{C}$ , Per Diode	150	A
$I_{FSM}$	Non-Repetitive Surge Forward Current	$T_J=45^{\circ}\text{C}$ , $t=10\text{ms}$ , 50Hz, Sine	1200	A
		$T_J=45^{\circ}\text{C}$ , $t=8.3\text{ms}$ , 60Hz, Sine	1310	A
$I^2t$	$I^2t$ (For Fusing)	$T_J=45^{\circ}\text{C}$ , $t=10\text{ms}$ , 50Hz, Sine	7200	$\text{A}^2\text{s}$
		$T_J=45^{\circ}\text{C}$ , $t=8.3\text{ms}$ , 60Hz, Sine	7122	$\text{A}^2\text{s}$
$P_D$	Power Dissipation		625	W
$T_J$	Junction Temperature		-40 to +150	$^{\circ}\text{C}$
$T_{STG}$	Storage Temperature Range		-40 to +125	$^{\circ}\text{C}$
Torque	Module-to-Sink	Recommended (M6)	3~4.7	N.m
Torque	Module Electrodes	Recommended (M6)	3~4.7	N.m
$R_{\theta C}$	Thermal Resistance	Junction-to-Case, Per Diode	0.2	$^{\circ}\text{C} / \text{W}$
Weight			92	g

### ELECTRICAL CHARACTERISTICS

$T_C=25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{RM}$	Reverse Leakage Current	$V_R=400\text{V}$	--	--	0.5	mA
		$V_R=400\text{V}, T_J=125^\circ\text{C}$	--	--	10	mA
$V_F$	Forward Voltage	$I_F=100\text{A}$	--	1.5	2.0	V
		$I_F=100\text{A}, T_J=125^\circ\text{C}$	--	1.2	--	V
$t_{rr}$	Reverse Recovery Time	$I_F=1\text{A}, V_R=30\text{V}, di_F/dt=-200\text{A}/\mu\text{s}$	--	35	--	ns
$t_{rr}$	Reverse Recovery Time	$V_R=200\text{V}, I_F=100\text{A}$	--	60	--	ns
$I_{RRM}$	Max. Reverse Recovery Current	$di_F/dt=-200\text{A}/\mu\text{s}, T_J=25^\circ\text{C}$	--	9	--	A
$t_{rr}$	Reverse Recovery Time	$V_R=200\text{V}, I_F=100\text{A}$	--	85	--	ns
$I_{RRM}$	Max. Reverse Recovery Current	$di_F/dt=-200\text{A}/\mu\text{s}, T_J=125^\circ\text{C}$	--	15	--	A

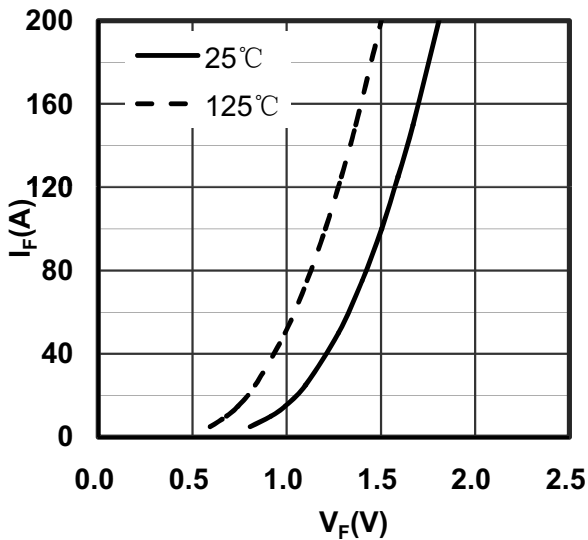


Figure 1. Forward Voltage Drop vs Forward Current

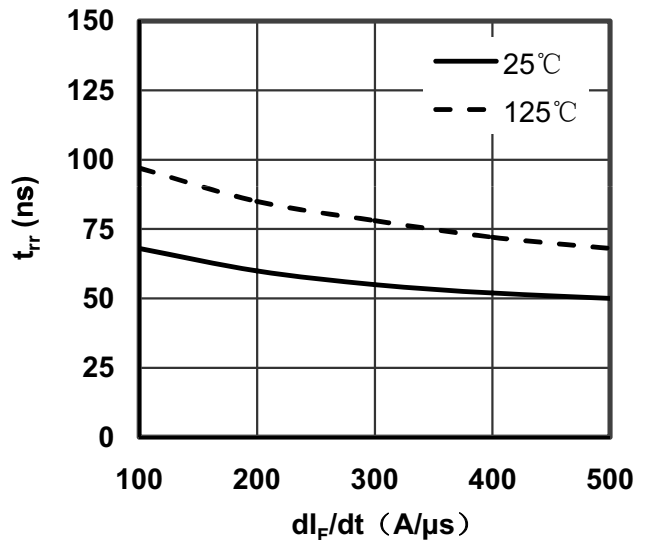


Figure 2. Reverse Recovery Time vs  $di/dt$

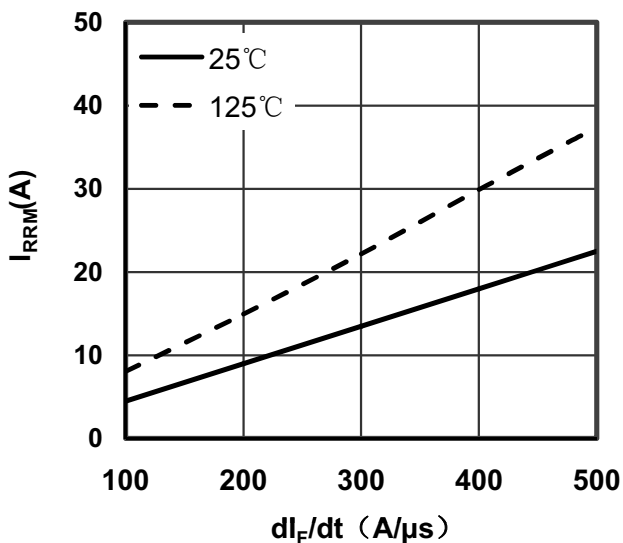


Figure 3. Reverse Recovery Current vs  $di/dt$

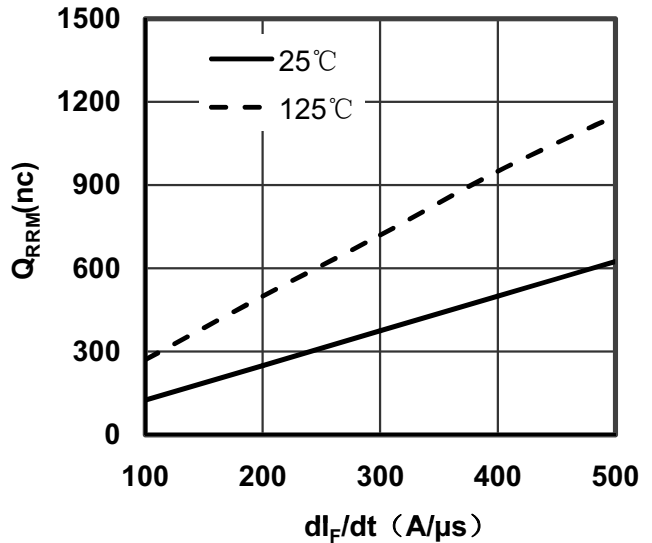


Figure 4. Reverse Recovery Charge vs  $di/dt$

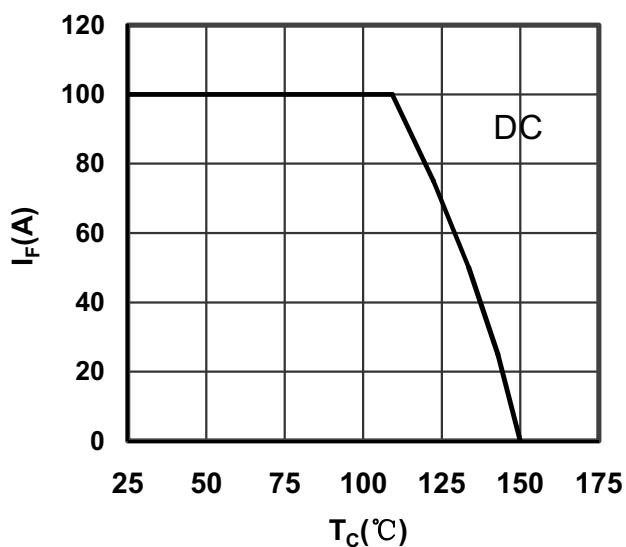


Figure 5. Forward current vs Case temperature

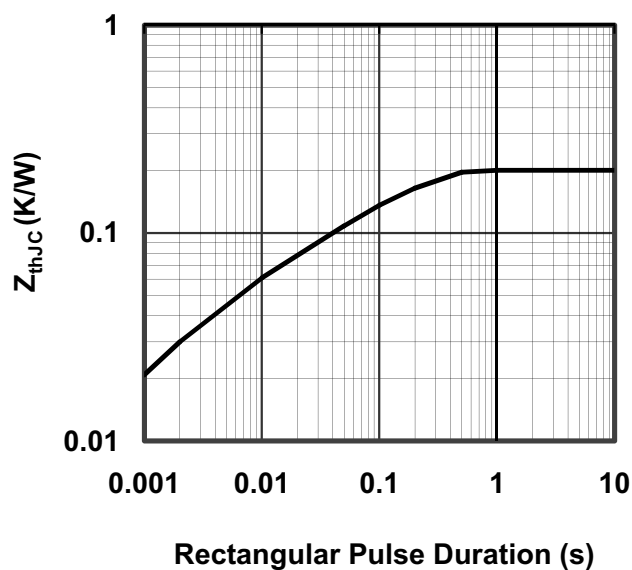
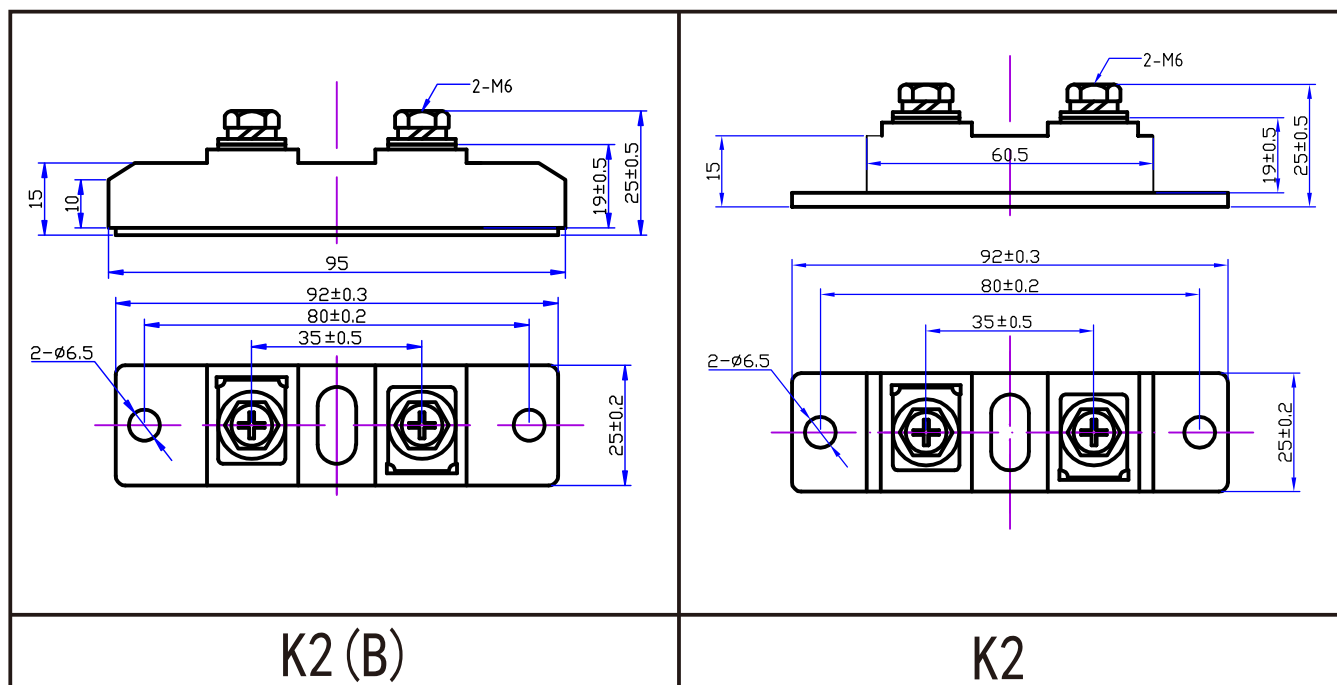


Figure 6. Transient Thermal Impedance

## Package Outlines



Unit:mm